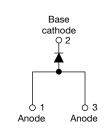


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## High Voltage Surface Mount Input Rectifier Diode, 25 A





PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub>	25 A						
V <sub>R</sub>	800 V, 1000 V, 1200 V						
V <sub>F</sub> at I <sub>F</sub>	1.14 V						
I <sub>FSM</sub>	300 A						
T <sub>j</sub> max.	150 °C						
Package	D <sup>2</sup> PAK (TO-263AB)						
Circuit configuration	Single						

#### **FEATURES**

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C



- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **APPLICATIONS**

- Input rectification
- Vishay switches and output rectifiers which are available in identical package outlines

#### **DESCRIPTION**

The VS-25ETS..S-M3 rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS								
Capacitive input filter T <sub>A</sub> = 55 °C, T <sub>J</sub> = 125 °C common heatsink of 1 °C/W	20	23	А					

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	UNITS								
I <sub>F(AV)</sub>	Sinusoidal waveform	25	A						
$V_{RRM}$		800 to 1200	V						
I <sub>FSM</sub>		300	A						
$V_{F}$	10 A, T <sub>J</sub> = 25 °C	1.0	V						
$T_J$		-40 to +150	°C						

VOLTAGE RATINGS									
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA						
VS-25ETS08S-M3	800	900							
VS-25ETS10S-M3	1000	1100	1						
VS-25ETS12S-M3	1200	1300							

ABSOLUTE MAXIMUM RATINGS								
PARAMETER SYMBOL TEST CONDITIONS VALUES UNITS								
Maximum average forward current I <sub>F(A'</sub>		T <sub>C</sub> = 106 °C, 180° conduction half sine wave	25					
Maximum peak one cycle	I	10 ms sine pulse, rated V <sub>RRM</sub> applied	250	Α				
non-repetitive surge current	I <sub>FSM</sub>	10 ms sine pulse, no voltage reapplied	300	1				
Maximum I <sup>2</sup> t for fusing	I <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	316	A <sup>2</sup> s				
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	442	A-S				
Maximum $I^2\sqrt{t}$ for fusing $I^2\sqrt{t}$ $t = 0.1$ ms to 10 ms,		t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s				

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ELECTRICAL SPECIFICATIONS								
PARAMETER SYMBOL TEST CONDITIONS VALUES UNITS								
Maximum forward voltage drop	$V_{FM}$	25 A, T <sub>J</sub> = 25 °C	1.14	V				
Forward slope resistance	r <sub>t</sub>	T - 150 °C	9.62	m $Ω$				
Threshold voltage	V <sub>F(TO)</sub>	1J = 150 C	T <sub>J</sub> = 150 °C					
Maximum reverse leakage current	l	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>RRM</sub>	0.1	mA			
waxiinum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	v <sub>R</sub> = nateu v <sub>RRM</sub>	1.0	IIIA			

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C			
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation 0.9					
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		62	°C/W			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth, and greased					
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting toward	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf ⋅ in)			
Marking device				25ETS08S				
			Case style D <sup>2</sup> PAK (TO-263AB)	25ETS10S				
				25ETS12S				

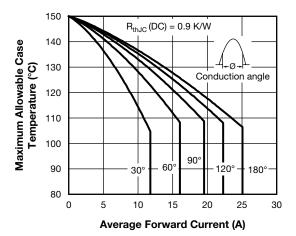


Fig. 1 - Current Rating Characteristics

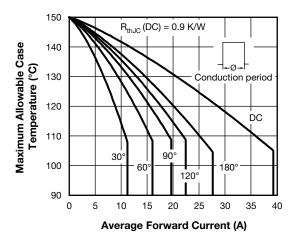


Fig. 2 - Current Rating Characteristics

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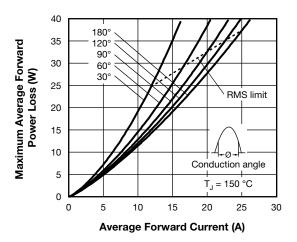


Fig. 3 - Forward Power Loss Characteristics

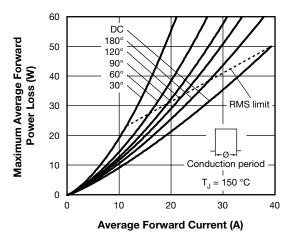


Fig. 4 - Forward Power Loss Characteristics

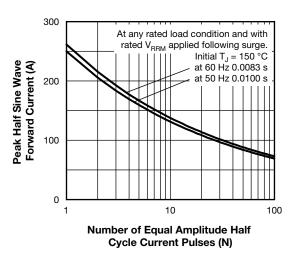


Fig. 5 - Maximum Non-Repetitive Surge Current

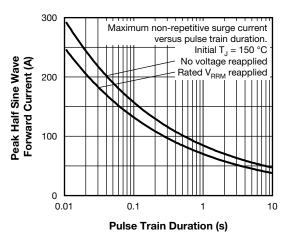


Fig. 6 - Maximum Non-Repetitive Surge Current

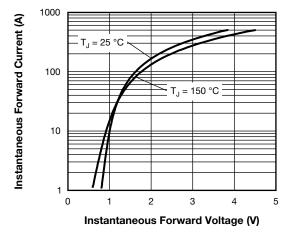


Fig. 7 - Forward Voltage Drop Characteristics

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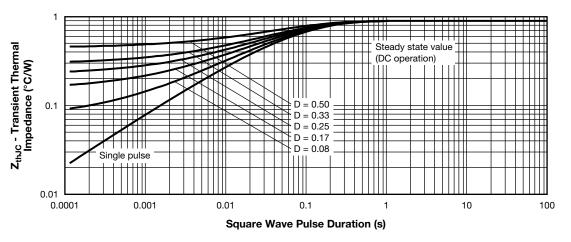
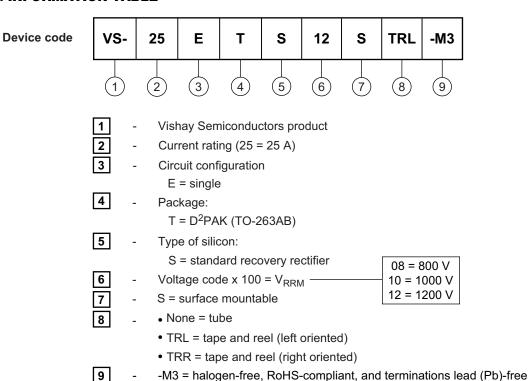


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

#### **ORDERING INFORMATION TABLE**





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ORDERING INFORMATION (Example)									
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION							
VS-25ETS08S-M3	50	Antistatic plastic tube							
VS-25ETS08STRR-M3	800	13" diameter reel							
VS-25ETS08STRL-M3	800	13" diameter reel							
VS-25ETS10S-M3	50	Antistatic plastic tube							
VS-25ETS10STRR-M3	800	13" diameter reel							
VS-25ETS10STRL-M3	800	13" diameter reel							
VS-25ETS12S-M3	50	Antistatic plastic tube							
VS-25ETS12STRR-M3	800	13" diameter reel							
VS-25ETS12STRL-M3	800	13" diameter reel							

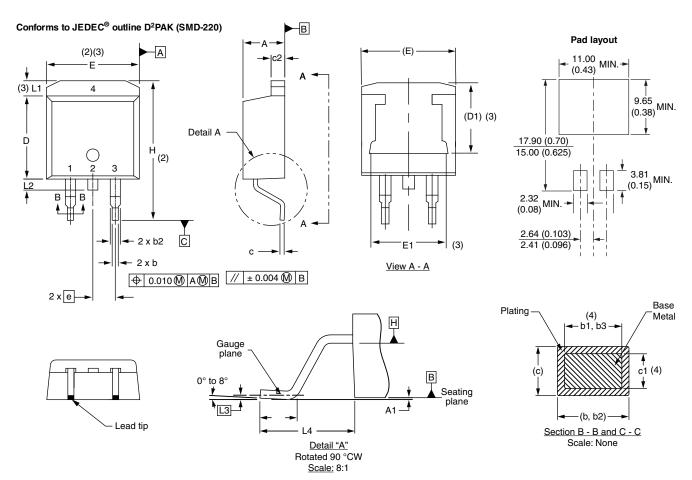
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?96164</u>						
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96424					



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### D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES		SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOIES	STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

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